

DOCKET NO: 242110US2S DIV

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :
KEIJI HOSOTANI ET AL : EXAMINER: NOT YET ASSIGNED
SERIAL NO: NEW APPLICATION :
FILED: HEREWITH : GROUP ART UNIT: NOT YET ASSIGNED
FOR: SEMICONDUCTOR MEMORY :
DEVICE USING MAGNETO
RESISTIVE ELEMENT AND
METHOD OF MANUFACTURING
THE SAME

PRELIMINARY AMENDMENT

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

Prior to an action on the merits, please amend the above-identified divisional application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 4 of this paper.

Remarks/Arguments begin on page 6 of this paper.